

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

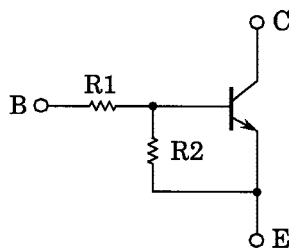
RN1701,RN1702,RN1703 RN1704,RN1705,RN1706

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

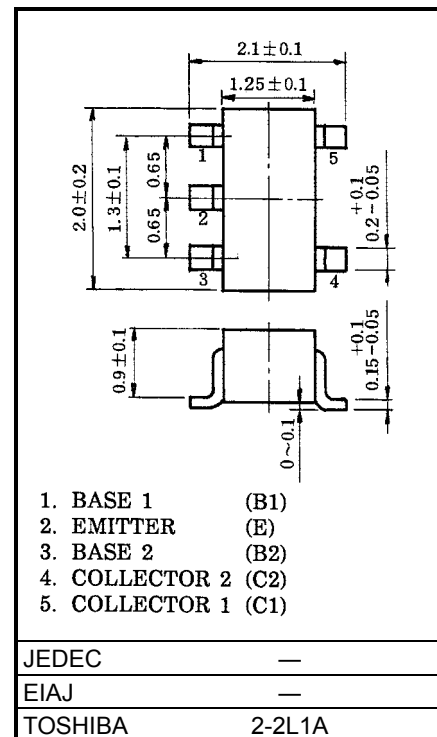
Unit: mm

- Including two devices in USV (ultra super mini type with 5 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2701~RN2706

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1701	4.7	4.7
RN1702	10	10
RN1703	22	22
RN1704	47	47
RN1705	2.2	47
RN1706	4.7	47



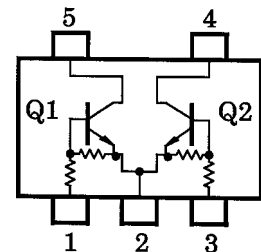
Weight: 6.2mg

Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	10	V
		5	V
Collector current	I_c	100	mA
Collector power dissipation	P_c^*	200	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

*: Total rating



Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1701~1706	I_{CBO}	—	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
		I_{CEO}	—	$V_{CE} = 50V, I_B = 0$	—	—	500	
Emitter cut-off current	RN1701	I_{EBO}	—	$V_{EB} = 10V, I_C = 0$	0.82	—	1.52	mA
	RN1702		—		0.38	—	0.71	
	RN1703		—		0.17	—	0.33	
	RN1704		—		0.082	—	0.15	
	RN1705		—	$V_{EB} = 5V, I_C = 0$	0.078	—	0.145	
	RN1706		—		0.074	—	0.138	
DC current gain	RN1701	h_{FE}	—	$V_{CE} = 5V, I_C = 10mA$	30	—	—	—
	RN1702		—		50	—	—	
	RN1703		—		70	—	—	
	RN1704		—		80	—	—	
	RN1705		—		80	—	—	
	RN1706		—		80	—	—	
Collector-emitter saturation voltage	RN1701~1706	$V_{CE(sat)}$	—	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Input voltage (ON)	RN1701	$V_{I(ON)}$	—	$V_{CE} = 0.2V, I_C = 5mA$	1.1	—	2.0	V
	RN1702		—		1.2	—	2.4	
	RN1703		—		1.3	—	3.0	
	RN1704		—		1.5	—	5.0	
	RN1705		—		0.6	—	1.1	
	RN1706		—		0.7	—	1.3	
Input voltage (OFF)	RN1701~1704	$V_{I(OFF)}$	—	$V_{CE} = 5V, I_C = 0.1mA$	1.0	—	1.5	V
	RN1705, 1706		—		0.5	—	0.8	
Translation frequency	RN1701~1706	f_T	—	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector output capacitance	RN1701~1706	C_{ob}	—	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3	6	pF
Input resistor	RN1701	R1	—	—	3.29	4.7	6.11	kΩ
	RN1702		—		7	10	13	
	RN1703		—		15.4	22	28.6	
	RN1704		—		32.9	47	61.1	
	RN1705		—		1.54	2.2	2.86	
	RN1706		—		3.29	4.7	6.11	
Resistor ratio	RN1701~1705	R1/R2	—	—	0.9	1.0	1.1	—
	RN1705		—		0.0421	0.0468	0.0515	
	RN1706		—		0.09	0.1	0.11	

(Q1, Q2 Common)

